

## **Standard Diodes** (Super MAGN-A-PAK Power Modules), 600 A



Super MAGN-A-PAK

| PRIMARY CHARACTERISTICS |                               |  |  |
|-------------------------|-------------------------------|--|--|
| I <sub>F(AV)</sub>      | 600 A                         |  |  |
| Type                    | Modules - diode, high voltage |  |  |
| Package                 | Super MAGN-A-PAK              |  |  |
| Circuit configuration   | Two diodes doubler circuit    |  |  |

#### **FEATURES**

- · High current capability
- High surge capability
- High voltage ratings up to 2000 V
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- · Industrial standard package
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

#### **TYPICAL APPLICATIONS**

- Rectifying bridge for large motor drives
- Rectifying bridge for large UPS

| MAJOR RATINGS AND CHARACTERISTICS |                 |             |                    |  |
|-----------------------------------|-----------------|-------------|--------------------|--|
| SYMBOL                            | CHARACTERISTICS | VALUES      | UNITS              |  |
| 1                                 |                 | 600         | A                  |  |
| I <sub>F(AV)</sub>                | T <sub>C</sub>  | 100         | °C                 |  |
| 1                                 |                 | 942         | А                  |  |
| I <sub>F</sub> (RMS)              | T <sub>C</sub>  | 100         | °C                 |  |
| I <sub>FSM</sub>                  | 50 Hz           | 19 000      | ^                  |  |
|                                   | 60 Hz           | 20 100      | A                  |  |
| l <sup>2</sup> t                  | 50 Hz           | 1805        | kA <sup>2</sup> s  |  |
|                                   | 60 Hz           | 1683        | KA-S               |  |
| I <sup>2</sup> √t                 |                 | 18 050      | kA <sup>2</sup> √s |  |
| $V_{RRM}$                         | Range           | 800 to 2000 | V                  |  |
| T <sub>Stg</sub> , T <sub>J</sub> | Range           | -40 to +150 | °C                 |  |

#### **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS |                 |  |  |   |  |  |
|-----------------|-----------------|--|--|---|--|--|
| TYPE NUMBER     | VOLTAGE<br>CODE | V <sub>RRM</sub> , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> MAXIMUM<br>AT T <sub>J</sub> MAXIMUM<br>mA |  |  |
|                 | 08              | 800  | 900  |   |  |  |
| VS-VSKD600 12   |                 | 1200   | 1300   | 50  |  |  |
| V3-V3ND000      | 16              | 1600   | 1700   | 50  |  |  |
|                 | 20              | 2000   | 2100   |   |  |  |



| FORWARD CONDUCTION                           |                     |   |                        |                                   |       |                   |
|--|---------------------|---|------------------------|-----------------------------------|-------|-------------------|
| PARAMETER                                    | SYMBOL              | TEST CONDITIONS   |                        | VALUES                            | UNITS |                   |
| Maximum average forward current              |                     | 190° condi  | uction, half sine      | ) WOVO                            | 600   | Α                 |
| at case temperature                          | I <sub>F(AV)</sub>  | 160 Condi   | uction, nan sine       | e wave                            | 100   | °C                |
| Maximum RMS forward current                  | I <sub>F(RMS)</sub> | 180° condi  | uction, half sine      | e wave at T <sub>C</sub> = 100 °C | 942   | Α                 |
|  |                     | t = 10 ms   | No voltage             |                                   | 19.0  |                   |
| Maximum peak, one-cycle forward,             | 1                   | t = 8.3  ms   | reapplied              | Sinusoidal half wave,             | 20.1  | kA                |
| non-repetitive surge current                 | I <sub>FSM</sub>    | t = 10 ms   | 100 % V <sub>RRM</sub> |                                   | 16.2  |                   |
|  |                     | t = 8.3  ms   | reapplied              |                                   | 17.2  |                   |
| Maximum I <sup>2</sup> t for fusing          | l <sup>2</sup> t    | t = 10 ms   | No voltage             | initial $T_J = T_J$ maximum       | 1805  |                   |
|  |                     | t = 8.3  ms   | reapplied              |                                   | 1683  | kA <sup>2</sup> s |
|  |                     | t = 10 ms   | 100 % V <sub>RRM</sub> |                                   | 1319  |                   |
|  |                     | t = 8.3  ms   | reapplied              |                                   | 1230  |                   |
| Maximum I <sup>2</sup> √t for fusing         | I²√t                | t = 0.1 ms to 10 ms, no voltage reapplied   |                        | 18 050                            | kA²√s |                   |
| Low level value of threshold voltage         | V <sub>F(TO)1</sub> | (16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum      |                        | 0.70                              | V     |                   |
| High level value of threshold voltage        | V <sub>F(TO)2</sub> | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$                             |                        | 0.77                              | V     |                   |
| Low level value of forward slope resistance  | r <sub>f1</sub>     | (16.7 % x $\pi$ x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum 0.3    |                        | 0.28                              | mΩ    |                   |
| High level value of forward slope resistance | r <sub>f2</sub>     | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ 0.25                        |                        | 11177                             |       |                   |
| Maximum forward voltage drop                 | $V_{FM}$            | $I_{pk} = 1800 \text{ A}, T_J = 25 \text{ °C}, t_p = 10 \text{ ms sine pulse}$ 1.45 |                        | V                                 |       |                   |

| BLOCKING   |                  |  |        |       |
|--|------------------|--|--------|-------|
| PARAMETER  | SYMBOL           | TEST CONDITIONS                              | VALUES | UNITS |
| RMS insulation voltage                             | V <sub>INS</sub> | t = 1 s                                      | 3000   | V     |
| Maximum peak reverse and off-state leakage current | I <sub>RRM</sub> | $T_J = T_J$ maximum, rated $V_{RRM}$ applied | 50     | mA    |

| THERMAL AND MECHANICAL SPECIFICATIONS                     |                                   |  |             |         |
|---|-----------------------------------|--|-------------|---------|
| PARAMETER   | SYMBOL                            | TEST CONDITIONS  | VALUES      | UNITS   |
| Maximum junction operating and storage temperature range  | T <sub>J</sub> , T <sub>Stg</sub> |  | -40 to +150 | °C      |
| Maximum thermal resistance, junction to case per junction | R <sub>thJC</sub>                 | DC operation   | 0.065       | K/W     |
| Maximum thermal resistance, case to heatsink per module   | R <sub>thC-hs</sub>               | Mounting surface smooth, flat and greased  | 0.02        | N/VV    |
| Mounting Super MAGN-A-PAK to heatsink                     |                                   |  | 6 to 8      |         |
| torque<br>± 10 % busbar to Super MAGN-A-PAK               |                                   | torque should be rechecked after a period of 3 hours to allow for the spread of the compound | 12 to 15    | Nm      |
| Approximate weight  |                                   |  | 1500        | g       |
| Case style  |                                   | See dimensions - link at the end of datasheet  | Super MAGN  | I-A-PAK |

| △R <sub>th</sub> JC CONDUCTION |                       |                        |                             |       |  |
|--------------------------------|-----------------------|------------------------|-----------------------------|-------|--|
| CONDUCTION ANGLE               | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS             | UNITS |  |
| 180°                           | 0.009                 | 0.006                  |                             |       |  |
| 120°                           | 0.011                 | 0.011                  |                             |       |  |
| 90°                            | 0.014                 | 0.015                  | $T_J = T_J \text{ maximum}$ | K/W   |  |
| 60°                            | 0.021                 | 0.022                  |                             |       |  |
| 30°                            | 0.037                 | 0.038                  |                             |       |  |

#### Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

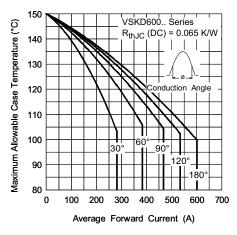


Fig. 1 - Current Ratings Characteristics

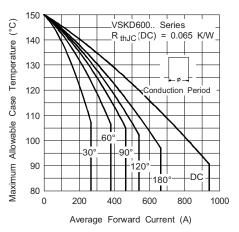


Fig. 2 - Current Ratings Characteristics

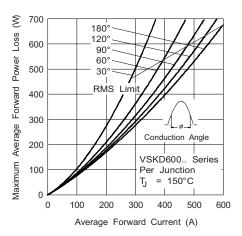


Fig. 3 - Forward Power Loss Characteristics

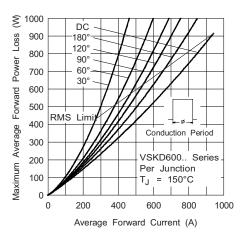


Fig. 4 - Forward Power Loss Characteristics

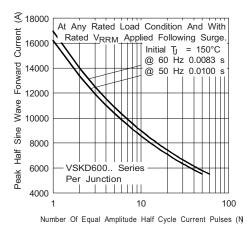


Fig. 5 - Maximum Non-Repetitive Surge Current

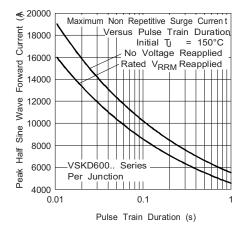


Fig. 6 - Maximum Non-Repetitive Surge Current

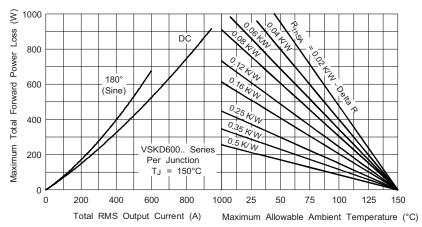


Fig. 7 - Forward Power Loss Characteristics

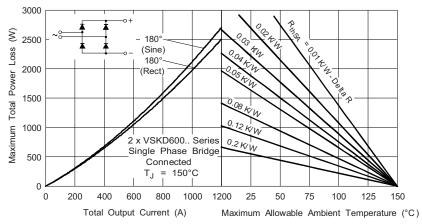


Fig. 8 - Forward Power Loss Characteristics

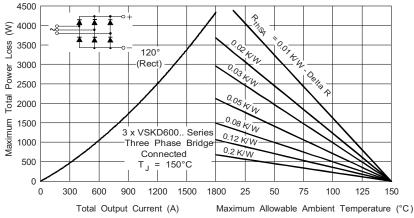


Fig. 9 - Forward Power Loss Characteristics

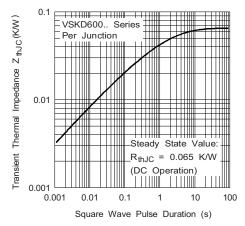
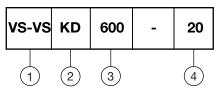


Fig. 10 - Thermal Impedance  $Z_{\text{thJC}}$  Characteristic

#### **ORDERING INFORMATION TABLE**

**Device code** 



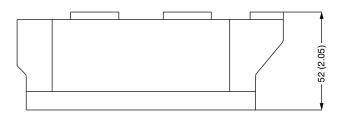
- Vishay Semiconductors product
- Circuit configuration D = two diodes in series (see circuit configuration table)
- Current rating
- Voltage code x 100 = V<sub>RRM</sub> (see voltage ratings table)

| CIRCUIT CONFIGURATION      |                               |                 |  |
|----------------------------|-------------------------------|-----------------|--|
| CIRCUIT DESCRIPTION        | CIRCUIT<br>CONFIGURATION CODE | CIRCUIT DRAWING |  |
| Two diodes doubler circuit | KD                            | 20 0 1          |  |

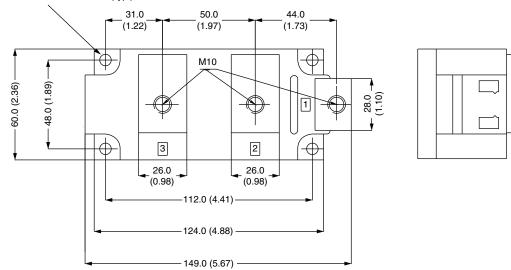
| LINKS TO RELATED DOCUMENTS |                          |  |
|----------------------------|--------------------------|--|
| Dimensions                 | www.vishay.com/doc?95088 |  |

# **Super MAGN-A-PAK Diode**

#### **DIMENSIONS** in millimeters (inches)



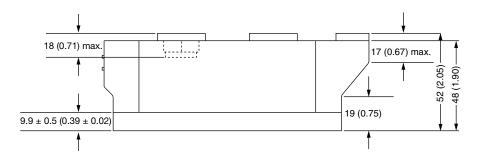
 $\emptyset$  6.5 mm  $\pm$  0.3 mm x 4 Holes (Typ.)

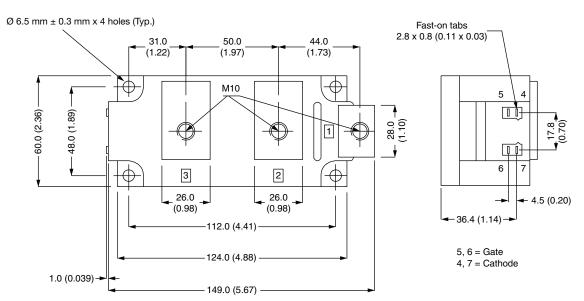




# **Super MAGN-A-PAK Thyristor/Diode**

#### **DIMENSIONS** in millimeters (inches)





### **Legal Disclaimer Notice**



Vishay

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